

[TPSM8287A06](https://www.ti.com.cn/product/cn/tpsm8287a06?qgpn=tpsm8287a06), [TPSM8287A10,](https://www.ti.com.cn/product/cn/tpsm8287a10?qgpn=tpsm8287a10) [TPSM8287A12](https://www.ti.com.cn/product/cn/tpsm8287a12?qgpn=tpsm8287a12), [TPSM8287A15](https://www.ti.com.cn/product/cn/tpsm8287a15?qgpn=tpsm8287a15)

[ZHCSPT6D](https://www.ti.com.cn/cn/lit/pdf/ZHCSPT6) – JULY 2023 – REVISED JUNE 2024

TPSM8287Axx 具有 **I2C** 接口和遥感功能的 **2.7V** 至 **6V** 输入、**6A**、**10A**、**12A** 和 **15A** 可并联降压电源模块

1 特性

• ±0.8% 的输出电压精度

INSTRUMENTS

• 差分遥感

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- 可并联实现多相操作
- 通过 VSETx 引脚在 0.40V 至 3.35V 范围内以 50mV 阶跃选择启动输出电压, I²C 可以 1.25mV 为 阶跃进行调节
- 通过 VSETx 引脚可选择 5 个 I²C 地址
- 可调节外部补偿,用于宽输出电容器范围和优化的 瞬态响应
- 进行了优化,可满足低 EMI 要求
	- 无键合线封装
	- 内部输入电容
	- 通过并行输入路径简化了布局
	- 可选择与外部时钟或展频运行同步
	- 节电模式或强制 PWM 运行
- 精密使能输入阈值
- 具有窗口比较器的电源正常输出
- 有源输出放电
- [优异的热性能](#page-53-0)
- -40°C 至 125°C 工作温度范围
- 间距为 0.5mm 的 4.5mm × 6.8mm QFN 封装
- 77mm² 解决方案尺寸

2 应用

- FPGA、ASIC [和数字内核电源](https://www.ti.com/design-resources/design-tools-simulation/processor-fpga-power/overview.html)
- [光纤网络](https://www.ti.com/design/optical-module)
- [存储](https://www.ti.com/applications/personal-electronics/data-storage/overview.html)
- DDR 存储器电源
- [测试和测量设备](https://www.ti.com/applications/industrial/test-measurement/overview.html)
- [传感器、成像和雷达](https://www.ti.com/applications/industrial/aerospace-defense/sensors-imaging-radar/overview.html)

3 说明

TPSM8287Axx 是具有差分遥感和 I2C 接口的引脚对引 脚直流/直流降压电源模块系列。该电源模块集成了同 步降压转换器、电感器和输入电容,可简化设计、减少 外部元件并节省印刷电路板 (PCB) 面积。该设计采用 紧凑的薄型封装,旨在通过标准表面贴装设备进行组 装。TPSM8287Axx 系列实现了可支持快速瞬变的增强 型控制方案。TPSM8287Axx 可以在固定频率或省电模 式下工作。遥感功能可优化负载点的电压调节,并且该 器件可在整个温度范围内实现 ±0.8% 的直流电压精 度。这些器件可在堆叠、并联模式下运行,以提供更高 的输出电流或将功耗分散到多个器件上。I²C 兼容接口 提供多种控制、监控和警告功能。可通过 VSETx 引脚 选择启动电压,以便在没有实际 I2C 通信的情况下实现 上电。

器件信息

益化 信息						
器件型号(2)	电流额定值	封装 ⁽¹⁾	封装高度			
TPSM8287A06BAS	6A	RDV				
TPSM8287A12BAS	12A	B0QFN, 39)	1.8mm			
TPSM8287A12BBS	12A					
TPSM8287A10BAH	10A	RDW				
TPSM8287A15BAH	15A	B3QFN, 39)	4.0 _{mm}			
TPSM8287A15BBH	15A					

(1) 有关更多信息,请参阅节 [12](#page-67-0)。

(2) 请参阅*[器件选项](#page-2-0)*表。

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准确性,请务必访问 ti.com 参考最新的英文版本 (控制文档)。

Table of Contents

4 Device Options

表 **4-1. Devices With I2C Interface**

(1) For all available packages, see the orderable addendum at the end of the data sheet.

5 Pin Configuration and Functions

图 **5-1. TPSM8287Axx RDV and RDW Package, B0QFN 39 Pin**

表 **5-1. Pin Functions**

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表 **5-1. Pin Functions** (续)

(1) $I = input$, $O = output$, $P = power$, $GND = ground$

6 Specifications

6.1 Absolute Maximum Ratings

over operating temperature range (unless otherwise noted) (1)

(1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.

(2) All voltage values are with respect to the GND pin.

(3) While switching.

6.2 ESD Ratings

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

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6.3 Recommended Operating Conditions (续)

(1) Whichever value is lower.

(2) *Effective* capacitance.

(3) In stacked operation, the maximum output current per phase could be reduced. See [Stacked Operation](#page-27-0) for details.

(4) The maximum recommended output capacitance depends on the specific operating conditions of an application. Output capacitance values up to a few mF are typically possible, however.

6.4 Thermal Information

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](http://www.ti.com/lit/SPRA953) application report.

(2) Not applicable to an EVM.

6.5 Electrical Characteristics

T_J = -40 °C to 125 °C, and V_{IN} = 2.7 V to 6 V. Typical values at V_{IN} = 3.3 V and T_J = 25 °C. (unless otherwise noted)

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6.5 Electrical Characteristics (续)

T_J = $-$ 40 °C to 125 °C, and V_{IN} = 2.7 V to 6 V. Typical values at V_{IN} = 3.3 V and T_J = 25 °C. (unless otherwise noted)

6.6 I ²C Interface Timing Characteristics

6.6 I2C Interface Timing Characteristics (续)

 (1) V_{DD} is the pullup voltage of SDA and SCL

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6.7 Typical Characteristics

7 Detailed Description

7.1 Overview

The TPSM8287Axx synchronous, step-down converter power modules use a fixed-frequency DCS-control topology to achieve fast transient response during a load step while switching with a fixed frequency during normal operation. This control topology, together with the low output voltage ripple, high DC accuracy and differential remote sense, makes them designed for supplying the cores of modern high-performance processors or other voltage rails with tight regulation requirements.

As the load current decreases, the converter can enter power save mode based on the MODE/SYNC pin, reducing the switching frequency and entering DCM to achieve high efficiency over the entire load current range.

This pin-to-pin compatible family of modules includes 6-A, 10-A, 12-A, and 15-A variants. To further increase the output current capability, combine multiple devices in a "stack". For example, paralleling four 15-A devices can provide up to 60 A of current.

7.2 Functional Block Diagram

(1) For inductance values please refer to $\bar{\mathcal{R}}$ [4-1](#page-2-0).

7.3 Feature Description

7.3.1 Fixed-Frequency DCS-Control Topology

 $\overline{8}$ 7-1 shows a simplified block diagram of the fixed-frequency DCS-control topology used in the TPSM8287Axx devices. This topology comprises an inner emulated current loop, a middle direct feedback loop, and an outer voltage-regulating loop. The differential remote sense allows for precise voltage regulation at the load. The external compensation allows fine tuning the load transient response for a wide range of output capacitance and load transient requirements.

图 **7-1. Fixed-Frequency DCS-Control Topology (Simplified)**

7.3.2 Forced-PWM and Power-Save Modes

The device can control the inductor current in three different ways to regulate the output:

- Pulse-width modulation with continuous inductor current (PWM-CCM)
- Pulse-width modulation with discontinuous inductor current (PWM-DCM)
- Pulse-frequency modulation with discontinuous inductor current and pulse skipping (PFM-DCM)

The on-time in PWM-CCM is set by 方程式 1. For very small output voltages, a minimum on time of approximately 50 ns (t_{ON min}) reduces the switching frequency from the set value. Even when the minimum ontime is reached, the device maintains proper output voltage regulation by extending the off-time.

$$
t_{ON} = \frac{V_{OUT}}{V_{IN} \times f_{SW}}\tag{1}
$$

During PWM-CCM operation, the device switches at a constant frequency and the inductor current is continuous (see \boxtimes [7-2](#page-13-0)). PWM operation achieves the lowest output voltage ripple and the best transient performance.

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图 **7-2. Continuous Conduction Mode (PWM-CCM) Current Waveform**

During PWM-DCM operation the device switches at a constant frequency and the inductor current is discontinuous (see \boxtimes 7-3). In this mode the device controls the peak inductor current to maintain the selected switching frequency while still being able to regulate the output.

方程式 2 is used to calculate the output current threshold at which the device changes from PWM-CCM to PWM-DCM:

图 **7-3. Discontinuous Conduction Mode (PWM-DCM) Current Waveform**

During PFM-DCM operation the device keeps the peak inductor current constant (at a level corresponding to an approximately 20-ns on-time of the converter) and skips pulses to regulate the output (see \boxtimes 7-4). The switching pulses that occur during PFM-DCM operation are synchronized to the internal clock.

图 **7-4. Discontinuous Conduction Mode (PFM-DCM) Current Waveform**

方程式 3 is used to calculate the output current threshold at which the device changes from PWM-DCM to PFM-DCM:

$$
I_{OUT(PFM-entry)} = \frac{V_{IN} \times 20 \text{ ns}}{2} \times \frac{1 - \frac{V_{OUT}}{V_{IN}}}{L}
$$
(3)

图 [7-5](#page-14-0) through 图 [7-7](#page-14-0) show how the PWM-DCM to PFM-DCM threshold typically varies with V_{IN} and V_{OUT}.

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Configure the device to use either Forced-PWM Mode (FPWM) or Power-Save Mode (PSM):

- In Forced-PWM mode, the device uses PWM-CCM at all times
- In Power-Save Mode, the device uses PWM-CCM at medium and high loads, PWM-DCM at light loads, and PFM-DCM at very light loads. Transitions between the different operating modes are seamless.

 $\bar{\textbf{x}}$ 7-1 shows the function table of the MODE/SYNC pin and the FPWMEN bit in the CONTROL1 register, which controls the operating mode of the device.

SSCEN Bit	FPWMEN Bit	MODE/SYNC Pin	OPERATING MODE	REMARK			
	0	Low	PSM	Do not use in a stacked configuration			
	0	Low	PSM				
0		X	FPWM				
0	х	High	FPWM				
Χ	X	Sync Clock	FPWM	see 节 7.3.8			
		х	FPWM	see 节 7.3.9			
	X	High	FPWM				

表 **7-1. FPWM Mode and Power-Save Mode Selection**

7.3.3 Precise Enable

The Enable (EN) pin is bidirectional and has two functions. See $\overline{8}$ 7-10:

- As an input, it enables and disables the DC/DC converter in the device
- In a stacked configuration, it is an output and provides a SYSTEM_READY signal to other devices.

图 **7-10. Enable Functional Block Diagram**

Because there is an internal open-drain transistor connected to the EN pin, do not drive this pin directly from a low-impedance source. Instead, use a > 15-kOhm resistor to limit the current flowing into the EN pin.

When power is first applied to the VIN pin, the device pulls the EN pin low until it loads the default register settings from nonvolatile memory and reads the state of the VSETx and SYNC_OUT pins. The device also pulls EN low if a fault, such as thermal shutdown or overvoltage lockout, occurs. In a stacked configuration all devices share a common enable signal, which means that the DC/DC converters in the stack cannot start to switch until *all* devices in the stack have completed the initialization. Similarly, a fault in one or more devices in the stack disables *all* converters in the stack (see 节 [7.3.17\)](#page-27-0).

In standalone (non-stacked) applications, set SINGLE = 1 in the CONTROL3 register to disable the active pulldown of the EN pin. Fault conditions have no effect on the EN pin when SINGLE = 1. (Note that the EN pin is *always* pulled down during device initialization.) In stacked applications, make sure that SINGLE = 0. Setting SINGLE = 1 also disables the SYNC_OUT pin.

When the internal SYSTEM READY signal is low (that is, initialization is complete and there are no fault conditions), the internal open-drain transistor is high impedance and the EN pin functions like a standard input: a

high level on the EN pin enables the DC/DC converter in the device and a low level disables it. The I²C interface is enabled as soon as the device has completed the initialization and is not affected by the state of the internal ENABLE or **SYSTEM_READY** signals.

A low level on the EN pin forces the device into shutdown. During shutdown, the MOSFETs in the power stage are off, the internal control circuitry is disabled, and the device consumes less than 20 µA (typical). Do not leave the EN pin floating.

The Precise Enable input provides a user-programmable undervoltage lockout by adding a resistor divider to the input of the EN pin. The Precise Enable input also allows the user to drive the pin by a slowly changing voltage and enables the use of an external RC network to achieve a precise power-up delay. See *[Achieving a clean](http://www.ti.com/lit/slyt730) [startup by using a DC/DC converter with a precise enable-pin threshold](http://www.ti.com/lit/slyt730)* analog design journal for more details.

7.3.4 Start-Up

When the voltage on the VIN pin exceeds the positive-going UVLO threshold, the device initializes as follows:

- The device pulls the EN pin low
- The device the internal reference voltage
- The device reads the state of the VSETx and SYNC_OUT pins
- The device loads the default values into the device registers

When initialization is complete, the device enables 12 C communication and releases the EN pin. The external circuitry controlling the EN pin now determines the behavior of the device:

- If the EN pin is low, the device is disabled:
	- The user can write to and read from the device registers
	- The power stage does not operate (high-impedance).
- If the EN pin is high, the device is enabled:
	- The user can write to and read from the device registers
	- After a short delay, the power stage starts switching
	- The converter ramps up the output voltage

 \boxtimes 7-11 shows the start-up sequence when the EN pin is pulled up to V_{IN} through a resistor.

图 7-11. Start-Up Timing When EN is Pulled Up to V_{IN}

 \boxtimes [7-12](#page-17-0) shows the start-up sequence when an external signal is connected to the EN pin.

图 **7-12. Start-Up Timing When an External Signal is Connected to the EN Pin**

The SSTIME[1:0] bits in the CONTROL2 register select the duration of the soft-start ramp:

- $t_{d(RAMP)} = 500 \mu s$
- $t_{d(RAMP)} = 1$ ms (default)
- $t_{d(RAMP)} = 2$ ms
- $t_{d(RAMP)} = 4$ ms

The device ignores new values during the soft-start sequence for the following parameters:

- Output voltage setpoint (VOUT[7:0])
- Output voltage range (VRANGE[1:0])
- Soft-start time (SSTIME[1:0])

If the user changes the value of VSET[7:0] during soft start, the device first ramps to the value that VSET[7:0] had when the soft-start sequence began. When soft start is complete, the device ramps up or down to the new value.

During start-up, the device does not sink current to make sure that the output voltage follows the configured ramp rate to the target output voltage. With this, the device can start up into a prebiased output. In this case, only a portion of the internal voltage ramp is seen externally (see $\boxed{\&}$ 7-13).

图 **7-13. Start-Up into a Prebiased Output**

7.3.5 Switching Frequency Selection

The TPSM8287Axx module family consists of device variants with different switching frequencies. For available options see $\bar{\textbf{\#}}$ [4-1](#page-2-0). The different switching frequencies allows the selection of the device which provides the best efficiency by optimizing the power losses for a given use case.

A lower switching frequency version does not necessarily offer a higher efficiency across the entire load, Vin or Vout range. The lower switching frequency does reduce the switching losses in the power stage, but at the same time leads to a higher ripple current in the inductor which leads to higher inductor losses, higher output voltage

ripple, and a lower maximum output current (see $\frac{1}{17}$ [7.3.13](#page-23-0)). Because of this, TI recommends to compare the efficiency when picking a certain device variant.

图 7-14 and 图 7-15 provide an efficiency comparison between the 1.5-MHz TPSM8287A12BAS and 2.25-MHz TPSM8287A12BBS. For output voltages ≥ 1.2 V, the efficiency between the 2.25-MHz and 1.5-MHz device is almost the same for high load currents, whereas the 2.25-MHz version gives higher efficiency at load currents below 3 A. The 1.5-MHz device generally gives higher efficiency for the other operating points, especially for lower output voltages. For output voltages >= 1.2 V, TI recommends the 2.25-MHz device for most applications due to the comparable efficiency, lower output voltage ripple, and higher maximum output current.

7.3.6 Output Voltage Setting

7.3.6.1 Output Voltage Setpoint

During initialization, the device reads the state of the VSETx pins and selects the default output voltage according to $\bar{\mathcal{R}}$ 7-2. Note that the VSETx pins also select the I²C target address of the device and the setting of the VRANGE bits located in register CONTROL2. The VSETx pins are only read during a power cycle of VIN or by setting RESET = 1 through the I²C interface. Changing the configuration after VIN is present does not affect the content of the registers or the I²C address. Make sure that there is no stray current path connected to the VSETx pins and that the parasitic capacitance between the VSETx pins and GND is less than 100 pF. For proper operation, the input voltage needs to be at least 1.4 V above the selected output voltage.

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表 **7-2. Start-Up Output Voltage and I2C Address** (续)

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(1) A second I2C address for the same output voltage is found at the bottom of this table

During start-up, the output voltage ramps up to the target value set by the VSETx pins before ramping up or down to any new value programmed to the device over the I²C interface. If the user programs new output voltage setpoints (VOUT[7:0]), output voltage range (VRANGE[1:0]), or soft-start time (SSTIME[1:0]) settings when the device has already begun the soft-start sequence, the device ignores the new values until the soft-start sequence is complete. When changing VOUT[7:0], VRAMP[1:0], or SSTIME[1:0] while EN is low, the device uses the new values the next time it is enabled.

7.3.6.2 Output Voltage Range

The device has four different output voltage ranges. The VRANGE[1:0] bits in the CONTROL2 register control which range is active (see $\frac{1}{6}$ 7-3). The default output voltage range is determined by the VSETx pins.

表 **7-3. Voltage Ranges**

Every change to the VRANGE[1:0] bits must be followed by a write to the VSET register – even if the value of the VSET[7:0] bits does not change. This sequence is necessary for the device to start to use the new voltage range.

When switching to or from the 0.8-V to 3.35-V range, the device switches the internal reference between 0.4 V and 0.8 V. To avoid any output voltage over or undershoot that can occur during the change, the VRANGE change must be done at an output voltage that occurs in both the new range and old range and the VSET[7:0] bits must set the same output voltage in both the new range and old range.

7.3.6.3 Non-Default Output Voltage Setpoint

If none of the output voltage setpoints in $\frac{1}{2}$ [7-2](#page-18-0) are suitable for the application, the user can change the output voltage through I2C *before enabling* the device. After the EN pin is pulled high, the device starts up and ramps to the desired output voltage set in the VSET register. A change of the device settings through I²C while the device is ramping are only be performed after the initial ramp is completed.

7.3.6.4 Dynamic Voltage Scaling (DVS)

If the user changes the output voltage setpoint while the device is operating, the device ramps up or down to the new voltage setting in a controlled way.

The VRAMP[1:0] bits in the CONTROL1 register set the slew rate when the device ramps from one voltage to another during DVS (see $\frac{1}{\sqrt{6}}$ 7-4). The ramp rate is independent of the setting of the VRANGE[1:0] bits.

If the MODE/SYNC pin is low and FPWMEN = 0, the slew rate can be less at low output currents because the device does not actively transfer energy back from the output capacitor to the input. At higher load currents the device controls the slew rate by transferring energy to the output.

Note that ramping the output to a higher voltage requires additional output current, so that during DVS the converter must generate a total output current given by:

$$
I_{\text{OUT}} = I_{\text{OUT (DC)}} + C_{\text{OUT}} \frac{dV_{\text{OUT}}}{dt}
$$

where:

- \cdot I_{OUT} is the total current the converter must generate while ramping to a higher voltage
- \cdot I_{OUT(DC)} is the DC load current
- \cdot C_{OUT} is the total output capacitance
- dV_{OUT}/dt is the slew rate of the output voltage (programmable in the range 0.5 mV/µs to 10 mV/µs)

For correct operation, make sure that the total output current during DVS does not exceed the rated current of the device.

7.3.7 Compensation (COMP)

The COMP pin is the connection point for an external compensation network. A series-connected resistor and capacitor to GOSNS is sufficient for typical applications and provides enough scope to optimize the loop response for a wide range of operating conditions.

(4)

When using multiple devices in a stacked configuration, all devices share a common compensation network, and the COMP pin makes sure equal current sharing between them (see $\ddot{\mathrm{t}}$ [7.3.17\)](#page-27-0).

7.3.8 Mode Selection / Clock Synchronization (MODE/SYNC)

A high level on the MODE/SYNC pin selects forced-PWM operation. A low level on the MODE/SYNC pin selects power-save operation, in which the device automatically transitions between PWM and PFM according to the load conditions.

If applying a valid clock signal to the MODE/SYNC pin, the device synchronizes the switching cycles to the external clock and automatically selects forced-PWM operation. When applying a frequency modulated clock to the MODE/SYNC pin, the device also follows this. This action can be useful in applications where the converter must follow an external Spread Spectrum Modulation.

The MODE/SYNC pin is logically ORed with the FPWMEN bit in the [CONTROL1](#page-37-0) register. Setting either high enables FPWM (see 节 [7.3.2](#page-12-0)).

When multiple devices are used in a stacked / parallel configuration to increase the output current, the clock signal from the primary device must cascade through all devices in a daisy chain configuration. The SYNC OUT pin of the previous device must connect to the MODE/SYNC pin of the next device in the chain (see $\ddot{\text{t}}$ [7.3.17](#page-27-0)).

7.3.9 Spread Spectrum Clocking (SSC)

The device has a spread spectrum clocking function which can reduce electromagnetic interference (EMI). When the SSC function is active, the device modulates the switching frequency to approximately ±10% around the nominal value. The frequency modulation has a triangular characteristic (see $\boxed{8}$ 7-16).

图 **7-16. Spread Spectrum Clocking Behavior**

To use the SSC function, make sure that:

- SSCEN = 1 in the CONTROL1 register
- The device is not synchronized to an external clock

TI recommends to use FPWM operation when using SSC, but SSC is available with PSM operation. To disable the SSC function, make sure that SCCEN = 0 in the CONTROL1 register.

7.3.10 Output Discharge

The device has an output discharge function which makes sure a defined ramp down of the output voltage when the device is disabled. The discharge stays on after the output is discharged. The output discharge function is enabled when DISCHEN = 1 in the CONTROL1 register.

If output discharge is enabled, the device discharges the output under the following conditions:

- A low level is applied to the EN pin
- SWEN = 0 in the CONTROL1 register
- A thermal shutdown event occurs
- An UVLO event occurs

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• An OVLO event occurs

When the output voltage is above 900 mV (typical), the discharge is about 115 mA. Below 900 mV, the discharge is about 3.5 Ohm. $\boxed{\otimes}$ 7-17 shows an example of the typical discharge behavior.

图 **7-17. Output Discharge**

The output discharge function is not available until the device has been enabled at least once after applying VIN. The output discharge functions until VIN drops to around 1.8 V.

In a stacked configuration, the discharge is always active in the secondary devices. Please refer to $\bar{\mathcal{R}}$ [7-6.](#page-29-0)

7.3.11 Undervoltage Lockout (UVLO)

The device has an undervoltage lockout function which disables the device if the supply voltage is too low for correct operation. The negative-going threshold of the UVLO function is 2.5 V (typical). If the supply voltage decreases below this value, the device stops switching and, if DISCHEN = 1 in the CONTROL1 register, turns on the output discharge. In addition, the EN pin is pulled low, which disables all other devices in the stack.

The device automatically starts switching again $-$ it begins a new soft-start sequence $-$ when the supply voltage is higher than 2.6 V (typical).

7.3.12 Overvoltage Lockout (OVLO)

The device has an overvoltage lockout function that disables the DC/DC converter if the supply voltage is too high for correct operation. The positive-going threshold of the OVLO function is 6.3 V (typical). If the supply voltage increases above this value, the device stops switching and, if DISCHEN = 1 in the CONTROL1 register, turns on the output discharge. In addition, the EN pin is pulled low, which disables all other devices in the stack.

The device automatically starts switching again $-$ it begins a new soft-start seguence $-$ when the supply voltage falls below 6.2 V (typical).

7.3.13 Overcurrent Protection

7.3.13.1 Cycle-by-Cycle Current Limiting

The TPSM8287Axx module is protected against overload and short circuit events. If the inductor current exceeds the high-side current limit, the high-side MOSFET is turned off and the low-side MOSFET is turned on to ramp down the inductor current. The high-side MOSFET turns on again only if the current in the low-side MOSFET has decreased below the low-side current limit. These current limits are designed to prevent the inductor of going into saturation. $\boxed{8}$ [7-18](#page-24-0) shows the typical input current in current limit.

图 **7-18. TPSM8287A12BBS Typical Input Current in Current Limit**

The low-side MOSFET also contains a negative current limit to prevent excessive current from flowing back through the inductor to the input. If the low-side sinking current limit is exceeded, the low-side MOSFET is turned off. In this scenario, both MOSFETs are off until the start of the next cycle. The negative current limit is only active in Forced PWM mode.

7.3.13.2 Hiccup Mode

Hiccup mode reduces the power dissipation during an overload event. To enable hiccup operation, make sure that HICCUPEN = 1 in the CONTROL1 register. If hiccup operation is enabled and the high-side switch current hits the high-side current limit threshold on 32 consecutive switching cycles, the device:

- Stops switching for 128 µs, after which the device automatically starts switching again (it starts a new softstart sequence)
- Sets the HICCUP bit in the STATUS register
- Pulls the PG pin low. The PG pin stays low until the overload condition goes away and the device can start up and regulate the output voltage.

Hiccup operation continues – in a repeating sequence of 32 cycles in current limit, followed by a pause of 128 μ s, followed by a soft-start attempt – for as long as the output overload condition exists.

The device clears the HICCUP bit if reading the STATUS register when the overload condition no longer exists. 图 7-19 shows 2 cycles of hiccup operation, at which point the over load is removed and the part continues in normal operation.

7.3.13.3 Current-Limit Mode

To enable current-limit mode, make sure that HICCUPEN = 0 in the CONTROL1 register.

When current limit operation is enabled, the device limits the high-side switch current cycle-by-cycle for as long as the overload condition exists. If the device limits the high-side switch current for four or more consecutive switching cycles, it sets ILIM = 1 in the STATUS register.

The device clears the ILIM bit if the user reads the STATUS register after the overload condition no longer exits.

7.3.14 Power Good (PG)

The Power-Good (PG) pin is bidirectional and has two functions:

- In a standalone configuration, and in the primary device of a stacked configuration, the PG pin is an opendrain output that indicates the status of the converter or stack.
- In a secondary device of a stacked configuration, the PG pin is an input that detects when the soft-start sequence is complete.

7.3.14.1 Power-Good Standalone, Primary Device Behavior

The primary purpose of the PG pin is to indicate if the output voltage is in regulation, but it also indicates if the device is in thermal shutdown or disabled. $\frac{1}{6}$ 7-5 summarizes the behavior of the PG pin in a stand-alone or primary device.

表 **7-5. Power-Good Function Table**

图 [7-21](#page-26-0) shows a functional block diagram of the power-good function in a stand-alone or primary device. A window comparator monitors the output voltage, and the output of the comparator goes high if the output voltage is either less than 94% (typical) or greater than 106% (typical) of the nominal output voltage. The output of the window comparator is deglitched – the typical deglitch time is 40 μ s (see $\&$ [7-20](#page-26-0)) – and then used to drive the open-drain PG pin.

图 **7-20. Power-Good Transient and Delay Behavior**

If an output under or overvoltage event occurs, the device sets the PBUV or PBOV bits in the STATUS register, respectively. The device clears the PBOV and PBUV bits if the user reads the STATUS register after the powerbad condition no longer exists.

During DVS activity, when the device transitions from one output voltage setting to another, the output voltage can temporarily exceed the limits of the window comparator and pull the PG pin low. The device has a feature to disable this behavior: if PGBLNKDVS = 1 in the CONTROL3 register, the device ignores the output of the powergood window comparator while DVS is active.

Note that the PG pin is always low - regardless of the output of the window comparator - when:

- The device is in thermal shutdown
- The device is in Hiccup mode
- The device is disabled
- The device is in undervoltage or overvoltage lockout (UVLO or OVLO)
- The device is in soft start

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7.3.14.2 Power-Good Secondary Device Behavior

In a stacked, parallel configuration, the PG signal is used to communicate between the devices. During device initialization, all devices in the stack pull the PG signal low. After each device completes the initialization, only the Primary device controls the PG signal and holds it low until soft start is completed.

The Secondary devices monitor the voltage level of the PG signal. When the PG signal is low, the secondary devices can not sink current until the primary device releases the PG signal. The external pullup resistor pulls PG high and the secondary devices operate in FPWM from that point onwards.

In case of a fault condition, the secondary device does not drive the PG signal but uses the EN pin to deactivate the whole stack. In this case, the Primary converter pulls the PG signal low. For details, see $\frac{1}{\sqrt{6}}$ [7-6](#page-29-0).

7.3.15 Remote Sense

The device has two pins, VOSNS and GOSNS, to remotely sense the output voltage. Remote sensing lets the converter sense the output voltage directly at the point-of-load and increases the accuracy of the output voltage regulation. These sense lines must be routed in parallel and away from noisy signals. Connect them to the lowest impedance point on the output bus, which must be the center of the output capacitor bank closest to the load.

In a stacked configuration, VOSNS and GOSNS of the primary and all secondary devices must be connected. For further details please see \ddagger 7.3.17.

7.3.16 Thermal Warning and Shutdown

The device has a two-level overtemperature detection function.

If the junction temperature rises above the thermal warning threshold of 150 °C (typical), the device sets the TWARN bit in the STATUS register. The device clears the TWARN bit if the STATUS register is read after the junction temperature fell below the TWARN threshold of 130 °C (typical).

If the junction temperature rises above the thermal shutdown threshold of 170 °C (typical), the device:

- Stops switching
- Pulls down the EN pin (if SINGLE $= 0$ in the CONTROL3 register)
- Enables the output discharge (if DISCHEN = 1 in the CONTROL1 register)
- Sets the TSHUT bit in the STATUS register
- Pulls the PG pin low

If the junction temperature then falls below the thermal shutdown threshold of 150 °C (typical), the device:

- Starts switching again, starting with a new soft-start sequence
- Releases the EN pin (high impedance)
- Releases the PG pin (high-impedance)

The device clears the TSHUT bit if the user reads the STATUS register after the junction temperature fell below the TSHUT threshold of 150 °C (typical).

In a stacked configuration, in which all devices share a common enable signal, a thermal shutdown condition in one device disables the entire stack. When the hot device cools down, the whole stack automatically starts switching again.

7.3.17 Stacked Operation

The user can connect multiple devices in parallel in what is known as a "stack" to increase output current capability, to reduce device junction temperature or the output voltage ripple. For example, paralleling four 15-A devices can provide up to 60 A of current. More devices can be stacked, as long as the PCB layout maintains the integrity of the shared signals between the modules.

A stack comprises one *primary* device and one or more *secondary* devices. During initialization, each device monitors the SYNC_OUT pin to determine if it must operate as a primary device or a secondary device:

- If there is a 47-k Ω resistor between the SYNC_OUT pin and ground, the device operates as a secondary device.
- If the SYNC_OUT pin is high impedance, the device operates as a primary device.

图 7-22 shows the recommended interconnections in a stack of two TPSM8287Axx devices.

The key points to note are:

- All the devices in the stack share a common enable signal, which must be pulled up with a resistance of at least 15 k Ω .
- All secondary devices must connect a 47-k Ω resistor between the SYNC OUT pin and ground.
- All the devices in the stack share a common power-good signal, which must be pulled up with a resistor to a logic high level.
- All the devices in the stack share a common compensation signal.
- The remote sense pins (VOSNS and GOSNS) *of each device* must be connected (do not leave these pins floating).
- The same device part number (with the same frequency and output current) must be used for all devices in the stack.
- The primary device must be configured for forced-PWM operation (secondary devices are automatically configured for forced-PWM operation).
- A stacked configuration can support synchronization to an external clock or spread-spectrum clocking.
- Only the VSETx pins of the primary device are used to set the default output voltage. The VSETx pins of secondary devices are not used and must be connected to ground.
- The SDA and SCL pins of secondary devices are not used and must be connected to ground.
- A stacked configuration uses a daisy-chained clocking signal, in which each device switches with a phase offset of approximately 140° relative to the previous device in the daisy-chain. To daisy-chain the clocking signal, connect the SYNC OUT pin of the primary device to the MODE/SYNC pin of the first secondary device. Connect the SYNC_OUT pin of the first secondary device to the MODE/SYNC pin of the second secondary device. Continue this connection scheme for all devices in the stack to daisy-chain them together.
- Hiccup overcurrent protection must not be used in a stacked configuration.
- For output voltages >=1.2V, reduce the maximum output current per phase by 1A to account for current balancing inaccuracy.

In a stacked configuration, the common enable signal also acts as a SYSTEM READY signal (see 节 [7.3.3](#page-15-0)). Each device in the stack can pull the EN pin low during device start-up or when a fault occurs. Thus, the stack is only enabled when all devices have completed the start-up sequence and are fault-free. A fault in any one device disables the whole stack for as long as the fault condition exists.

During start-up, the primary converter pulls the COMP pin low for as long as the enable signal (SYSTEM_READY) is low. When the enable signal goes high, the primary device actively controls the COMP pin and all converters in the stack follow the COMP voltage. During start-up, each device in the stack pulls the PG pin low while it initializes. When initialization is complete, each secondary device in the stack sets it PG pin to high impedance and the primary device alone controls the state of the PG signal. The PG pin goes high when the stack has completed the start-up ramp and the output voltage is within the power good window. The secondary converters in the stack detect the rising edge of the power-good signal and switch to FPWM operation. After the stack has successfully started up, the primary device controls the power-good signal in the normal way. In a stacked configuration, there are some faults that only affect individual devices, and other faults that affect all devices. For example, if one device enters current limit, only that device is affected. But a thermal shutdown or undervoltage lockout event in one device disables all devices through the shared enable (SYSTEM_READY) signal. For details refer to $\frac{1}{\mathcal{R}}$ [7-7](#page-30-0).

Functionality During Stacked Operation

Some device features are not available during stacked operation, or are only available in the primary converter. $\bar{\textbf{\#}}$ 7-6 summarizes the available functionality during stacked operation.

表 **7-6. Functionality During Stacked Operation**

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表 **7-6. Functionality During Stacked Operation** (续)

Fault Handling During Stacked Operation

In a stacked configuration, there are some faults that only affect individual devices, and other faults that affect all devices. For example, if one device enters current limit, only that device is affected. But a thermal shutdown or undervoltage lockout event in one device disables all devices through the shared enable (SYSTEM_READY) signal. $\bar{\textbf{x}}$ 7-7 summarizes the fault handling during stacked operation.

表 **7-7. Fault Handling During Stacked Operation**

7.4 Device Functional Modes

7.4.1 Power-On Reset (POR)

The device operates in POR mode when the supply voltage is less than the POR threshold (V_{POR}).

In POR mode, no functions are available and the device resets the registers to the default values.

The device leaves POR mode and enters UVLO mode when the supply voltage increases above the POR threshold.

7.4.2 Undervoltage Lockout

The device operates in UVLO mode when the supply voltage is between the POR and UVLO thresholds.

If the device enters UVLO mode from POR mode, no functions are available. If the device enters UVLO mode from Standby mode, the output discharge function is available. The I2C interface is not available in UVLO mode.

The device leaves UVLO mode and enters POR mode when the supply voltage decreases below the POR threshold. The device leaves UVLO mode and enters Standby mode when the supply voltage increases above the UVLO threshold.

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7.4.3 Standby

The device operates in Standby mode when the supply voltage is greater than the UVLO threshold and any of the following conditions is true:

- A low level is applied to the EN pin
- SWEN = 0 in the CONTROL1 register
- The device junction temperature is greater than the thermal shutdown threshold
- The supply voltage is greater than the OVLO threshold
- The device is initializing

The following functions are available in Standby mode:

- I²C Interface
- Output discharge
- Power-good

The device leaves Standby mode and enters UVLO mode when the supply voltage decreases below the UVLO threshold. The device leaves Standby mode and enters On mode when all of the following conditions are true:

- A high-level is applied to the EN pin
- SWEN = 1 in the CONTROL1 register
- The device junction temperature is below the thermal shutdown threshold
- The supply voltage is below the OVLO threshold

7.4.4 On

The device operates in On mode when the supply voltage is greater than the UVLO threshold and all of the following conditions are true:

- A high-level is applied to the EN pin
- SWEN = 1 in the CONTROL1 register
- The device junction temperature is below the thermal shutdown threshold
- The supply voltage is below the OVLO threshold

All functions are available in On mode.

The device leaves On mode and enters UVLO mode when the supply voltage decreases below the UVLO threshold. The device leaves On mode and enters the Standby mode when any of the following conditions is true:

- A low level is applied to the EN pin
- SWEN = 0 in the CONTROL1 register
- The device junction temperature is greater than the thermal shutdown threshold
- The supply voltage is greater than the OVLO threshold

7.5 Programming

7.5.1 Serial Interface Description

¹²C is a 2-wire serial interface developed by Philips Semiconductor, now NXP Semiconductors (see ¹²C-Bus Specification and User Manual, Revision 6, 4 April 2014). The bus consists of a data line (SDA) and a clock line (SCL) with pullup structures. When the bus is *idle*, both SDA and SCL lines are pulled high. All I2C-compatible devices connect to the I2C bus through open drain I/O pins, SDA and SCL. A *controller*, usually a microcontroller or a digital signal processor, controls the bus. The controller is responsible for generating the SCL signal and device addresses. The controller also generates specific conditions that indicate the START and STOP of data transfer. A *target* receives and transmits data on the bus under control of the controller.

The TPSM8287Axx device operates as a target and supports the following data transfer *modes*, as defined in the I²C-Bus Specification: standard mode (100 kbps), fast mode (400 kbps), and fast mode plus (1 Mbps). The interface adds flexibility to the power supply design, enabling most functions to be programmed to new values

depending on the instantaneous application requirements. Register contents remain intact as long as the input voltage remains above $V_{\text{POR-}}$.

The data transfer protocol for standard and fast modes is exactly the same, therefore they are referred to as F/Smode in this document. The device supports 7-bit addressing; general call addresses are not supported.

The state of the VSETx pins during power-up defines the $1²C$ target address of the device (see $\bar{\mathcal{R}}$ [7-2](#page-18-0)).

TI recommends that the $12C$ controller initiates a STOP condition on the $12C$ bus after the initial power up of the SDA and SCL pullup voltages to make sure a reset of the I²C engine.

7.5.2 Standard-, Fast-, Fast-Mode Plus Protocol

The controller initiates a data transfer by generating a start condition. The start condition is when a high-to-low transition occurs on the SDA line while SCL is high, as shown in $\&$ 7-23. All I²C-compatible devices must recognize a start condition.

图 **7-23. START and STOP Conditions**

The controller then generates the SCL pulses, and transmits the 7-bit address and the read/write direction bit R/ \overline{W} on the SDA line. During all transmissions, the controller makes sure that data is valid. A valid data condition requires the SDA line to be stable during the entire high period of the clock pulse (see \boxtimes 7-24). All devices recognize the address sent by the controller and compare it to the internal fixed addresses. Only the target with a matching address generates an acknowledge (see $\boxed{8}$ [7-25\)](#page-33-0) by pulling the SDA line low during the entire high period of the ninth SCL cycle. Upon detecting this acknowledge, the controller knows that communication link with a target has been established.

图 **7-24. Bit Transfer on the Serial Interface**

图 **7-25. Acknowledge on the I2C Bus**

The controller generates further SCL cycles to either transmit data to the target (R/W bit 0) or receive data from the target (R/W bit 1). In either case, the target must acknowledge the data sent by the controller. So an acknowledge signal can either be generated by the controller or by the target, depending on which one is the receiver. 9-bit valid data sequences consisting of 8-bit data and 1-bit acknowledge can continue as long as necessary (see $\boxed{8}$ 7-26).

To signal the end of the data transfer, the controller generates a stop condition by pulling the SDA line from low to high while the SCL line is high (see $\&$ [7-23](#page-32-0)). This action releases the bus and stops the communication link with the addressed target. All I²C-compatible devices must recognize the stop condition. Upon the receipt of a stop condition, all devices know that the bus is released, and the devices wait for a start condition followed by a matching address.

Attempting to read data from register addresses not listed in this section results in 0x00 being read out.

7.5.3 I ²C Update Sequence

A start condition, a valid ${}^{12}C$ address, a register address byte, and a data byte are required for a single update. After the receipt of each byte, the receiving device acknowledges by pulling the SDA line low during the high period of a single clock pulse. A valid I2C address selects the target. The target performs an update on the falling edge of the acknowledge signal that follows the LSB byte.

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1 7 1 1 8 1 8 1 1 \mathbf{I} S Device Address R/W A Register Address A Data A/A P $\begin{array}{c} | \\ 0" \end{array}$ Write $A =$ Acknowledge (SDA low) From Controller to Target \overline{A} = Not acknowledge (SDA high) From Target to Controller S = START condition Sr = REPEATED START condition P = STOP condition

7.5.4 I ²C Register Reset

The I^2C registers can be reset by:

- Pulling the input voltage below V_{POR} (see \ddagger [7.4.1](#page-30-0)).
- Setting the RESET bit in the CONTROL register. When RESET = 1, all registers are reset to the default values and a new start-up begins immediately. After $t_{d(EN)2}$, all I²C registers can be accessed again.

8 Device Registers

表 8-1 lists the Device registers. All register addresses not listed in $\frac{1}{36}$ 8-1 must be considered as reserved locations and the register contents must not be modified.

Complex bit access types are encoded to fit into small table cells. $\bar{\mathcal{R}}$ 8-2 shows the codes that are used for access types in this section.

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8.1 VSET Register (Address = 0h) [Reset = X]

VSET is shown in $\boxed{8}$ 8-1 and described in $\frac{1}{\sqrt{6}}$ 8-3.

Return to the [Summary Table.](#page-35-0)

This register controls the output voltage setpoint

表 **8-3. VSET Register Field Descriptions**

8.2 CONTROL1 Register (Address = 1h) [Reset = 2Ah]

CONTROL1 is shown in $\boxed{8}$ 8-2 and described in $\frac{1}{6}$ 8-4.

Return to the [Summary Table.](#page-35-0)

This register controls various device configuration options

表 **8-4. CONTROL1 Register Field Descriptions**

8.3 CONTROL2 Register (Address = 2h) [Reset = X]

CONTROL2 is shown in $\boxed{8}$ 8-3 and described in $\frac{1}{6}$ 8-5.

Return to the [Summary Table.](#page-35-0)

This register controls various device configuration options

表 **8-5. CONTROL2 Register Field Descriptions**

8.4 CONTROL3 Register (Address = 3h) [Reset = 0h]

CONTROL3 is shown in $\boxed{8}$ 8-4 and described in $\frac{1}{\sqrt{6}}$ 8-6.

Return to the [Summary Table.](#page-35-0)

This register controls various device configuration options

图 **8-4. CONTROL3 Register**

表 **8-6. CONTROL3 Register Field Descriptions**

8.5 STATUS Register (Address = 4h) [Reset = 2h]

STATUS is shown in \boxtimes 8-5 and described in $\ddot{\textless}$ 8-7.

Return to the [Summary Table.](#page-35-0)

This register returns the device status flags

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9 Application and Implementation

备注

以下应用部分中的信息不属于 TI 器件规格的范围,TI 不担保其准确性和完整性。TI 的客 户应负责确定 器件是否适用于其应用。客户应验证并测试其设计,以确保系统功能。

9.1 Application Information

The following section discusses selection of the external components to complete the power supply design for typical a application.

The required power inductor is integrated inside the TPSM8287Axx, as shown in the [block diagram.](#page-11-0) The integrated shielded inductor inductance and tolerance are found in $\frac{1}{2}$ [4-1](#page-2-0). All TPSM8287Axx versions are pin-topin compatible, though the inductance and frequency is different between the versions. Check the values for the specific device before starting the design procedure below.

9.2 Typical Application

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表 **9-1. List of Components** (续)

(1) See the *Third-Party Products Disclaimer* disclaimer.

9.2.1 Design Requirements

表 9-2 lists the operating parameters for this application example with the TPSM8287A12BBS device.

表 **9-2. Design Parameters**

Preliminary Calculations

The maximum allowable deviation of the power supply is ±3.8%. The DC accuracy of the TPSM8287Axx is specified as ±0.8%, and therefore the maximum output voltage variation during a transient is given by:

$$
\Delta V_{\text{OUT}} = \pm V_{\text{OUT}} \times (\text{TOL}_{\text{VOUT}} - \text{TOL}_{\text{DC}}) \tag{5}
$$

$$
\Delta V_{\text{OUT}} = \pm V_{\text{OUT}} \times (3.8\% - 0.8\%) = \pm 27 \,\text{mV}
$$
 (6)

方程式 7 computes the peak-to-peak inductor current ripple, which is the greatest at the maximum input voltage:

$$
I_{L(PP)} = \frac{V_{OUT}}{V_{IN(max)}} \left(\frac{V_{IN(max)} - V_{OUT}}{L \times f_{sw} \times N\Phi} \right)
$$
(7)

$$
I_{L(PP)} = \frac{0.9}{6.0} \left(\frac{6.0 - 0.9}{100 \times 10^{-9} \times 2.25 \times 10^{6} \times 1} \right) = 3.4 A
$$
 (8)

The maximum load step occurs when the load step from the application occurs at exactly the same time as the peak (or trough) of the inductor ripple current, and is given by:

$$
\Delta I_{\text{OUT(max)}} = \Delta I_{\text{OUT(step)}} + \frac{\Delta I_{\text{L(PP)}}}{2} \tag{9}
$$

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$$
\Delta I_{\text{OUT(max)}} = 8.0 + \frac{3.4}{2} = 9.7 \,\text{A} \tag{10}
$$

9.2.2 Detailed Design Procedure

The following subsections describe how to calculate the external components required to meet the specified transient requirements of a given application. The calculations include the worst-case variation of components and use the RMS method to combine the variation of uncorrelated parameters.

See *[TPSM8287A-COMPONENT-CALCULATOR](https://www.ti.com/tool/download/TPSM8287A-COMPONENT-CALCULATOR)* for a spreadsheet component calculator with the below calculations.

9.2.2.1 Selecting the Input Capacitors

The input capacitor buffers the input voltage for transient events and also decouples the converter from the supply. TI recommends a X7R multilayer ceramic capacitor (MLCC) for best filtering and must be placed between both VIN and GND pins, as close as possible to those pins. For applications with ambient temperatures below 85°C, a capacitor with X5R dielectric can be used. Ceramic capacitors have a DC-Bias effect, which has a strong influence on the final effective capacitance. Choose the right capacitor carefully in combination with considering the package size and voltage rating. The two high frequency input capacitors are placed inside the module to reduce EMI, shrink the overall design size and to simplify the board layout. As those integrated capacitors target high frequencies, additional external capacitors with a minimum of 5 µF are required per VIN pin.

The TPSM8287Axx devices feature a *butterfly* or parallel layout with two pairs of VIN and GND pins on opposite sides of the package. This feature allows the input capacitors to be placed symmetrically on the PCB so that the electromagnetic fields cancel each other out, thereby reducing EMI. In addition, the parasitic loop inductance between the input capacitors and the IC is reduced through this pinout.

The duty cycle of the converter is given by:

$$
D = \frac{V_{OUT}}{\eta \times V_{IN}}\tag{11}
$$

where:

- V_{IN} is the input voltage
- V_{OUT} is the output voltage
- η is the efficiency

$$
D = \frac{0.90}{0.83 \times 2.7} = 0.402 \tag{12}
$$

The value of input capacitance needed to meet any system-level input voltage ripple requirement is given by $\dot{\pi}$ 程式 13. For this example, the lowest input voltage and highest load current are used to generate a worst case input voltage ripple of 100 mV.

$$
C_{IN} = \frac{D \times (1 - D) \times I_{OUT}}{V_{IN(PP)} \times f_{sw}}
$$
(13)

where:

- D is the duty cycle
- f_{sw} is the switching frequency
- L is the inductance
- \cdot I_{OUT} is the output current

$$
C_{IN} = \frac{0.402 \times (1 - 0.402) \times 12.0}{0.1 \times 2.25 \times 10^6} = 12.8 \,\mu\text{F}
$$
\n⁽¹⁴⁾

The value of C_{IN} calculated with [方程式](#page-43-0) 13 is the *effective* capacitance after all derating, tolerance, and aging effects have been considered.

9.2.2.2 Selecting the Target Loop Bandwidth

The control loop bandwidth measures how quickly the device responds to a change in output voltage. With the TPSM8287Axx external compensation, the loop bandwidth is adjustable to balance the tradeoff of a fast response versus stability and ringing. The R_{Comn1} resistor and output capacitance are the primary means of adjusting the loop bandwidth.

TI recommends setting the target loop bandwidth to 200 kHz for a simple design. If strong load transients are expected in the application, the target bandwidth can be set as high as $\frac{1}{4}$ of the switching frequency. A target bandwidth of 300 kHz is used for this example design.

9.2.2.3 Selecting the Compensation Resistor

Use 方程式 15 to calculate the recommended value of compensation resistor, R_{Comp1}:

$$
R_{\text{Comp1}} = \frac{1}{g_{\text{m}}} \left(\frac{\pi \times \Delta I_{\text{OUT}(step)} \times L}{4 \times \tau \times \Delta V_{\text{OUT}} \times N\Phi} - 1 \right) \left(1 + \sqrt{\text{TOL}_{\text{IND}}^2 + \text{TOL}_{\tau}^2} \right) \tag{15}
$$

$$
R_{\text{Comp1}} = \frac{1}{1.5 \times 10^{-3}} \left(\frac{\pi \times 8.0 \times 100 \times 10^{-9}}{4 \times 12.5 \times 10^{-6} \times 27 \times 10^{-3} \times 1} - 1 \right) \left(1 + \sqrt{20\%^{2} + 30\%^{2}} \right) = 781.6 \ \Omega \tag{16}
$$

Picking a standard component above the calculated value, a 806-Ohm resistor is chosen in this example. The selected value must be used for the further calculations.

9.2.2.4 Selecting the Output Capacitors

In practice, the total output capacitance is typically comprised of a combination of different capacitors, in which larger capacitors provide the load current at lower frequencies and smaller capacitors provide the load current at higher frequencies to satisfy the load impedance requirements. The value, type, and location of the output capacitors are typically defined by the load. TI recommends X7R multilayer ceramic capacitors (MLCCs) for best filtering and must be placed between both VOUT and GND pins, as close as possible to those pins. For applications with ambient temperatures below 85°C, capacitors with an X5R dielectric can be used. Ceramic capacitors have a DC-Bias effect, which has a strong influence on the final effective capacitance. Choose the right capacitors carefully in combination with considering the package size and voltage rating. The below calculations use the effective value of the total output capacitance.

The TPSM8287Axx devices feature a *butterfly* or *parallel* layout with VOUT and GND pins on opposite sides of the package. This feature allows the output capacitors to be placed symmetrically on the PCB such that the electromagnetic fields cancel each other out, thereby reducing EMI.

The TPSM8287Axx device is optimized to support harsh load transients. The device external loop compensation tunes the loop response to the desired response with a given output capacitance. The below calculations create designs that meet the load step specified in $\frac{1}{100}$ 5-2. These calculations typically result in total output capacitances of several hundred µF.

Best output voltage regulation is achieved when the TPSM8287Axx device, the output capacitors, and load are placed very close to each other, keeping the distance and added inductance between the device and load to the absolute minimum.

In case this placement can not be achieved, then the majority of the total capacitance must be located at the load, with just two capacitors located at the TPSM8287Axx device. TI recommends that the capacitance located at the load be at least twice the amount of the capacitance located at the device.

If the application does not contain harsh load transients, then smaller values of output capacitances are possible. Do not use output capacitances below the minimum values in *[Recommended Operating Conditions](#page-5-0)*.

The transient response of the converter is defined by one of two criteria:

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- The slew rate of the current through the inductor, in which case the feedback loop of the converter saturates.
- The loop bandwidth, in which the converter stays in regulation, and the loop does not saturate (BW_T < f_{SW} / 4)

Which of the above criteria applies in any given application depends on the operating conditions and component values used. Calculate the output capacitance for both cases and select the higher of the two values.

If the converter remains in regulation, the minimum required output capacitance is given by:

$$
C_{OUT(min)(reg)} = \left(\frac{\tau \times (1 + g_m \times R_{Comp1})}{2 \times \pi \times \frac{L}{N\Phi} \times BW_{\tau}}\right) \left(1 + \sqrt{TOL_{\tau}^{2} + TOL_{IND}^{2} + TOL_{fSW}^{2}}\right)
$$
(17)

$$
C_{OUT(min)(reg)} = \left(\frac{12.5 \times 10^{-6} \times (1 + 1.5 \times 10^{-3} \times 806)}{2 \times \pi \times \frac{100 \times 10^{-9}}{1} \times 300 \times 10^{3}}\right) \left(1 + \sqrt{30\%^{2} + 20\%^{2} + 10\%^{2}}\right) = 201.3 \text{ }\mu\text{F}
$$
\n(18)

If the converter loop saturates, the minimum output capacitance is given by:

$$
C_{OUT(min)(sat)} = \frac{1}{\Delta V_{OUT}} \left(\frac{L \times \Delta I_{OUT(max)}^2}{2 \times V_{OUT} \times N\Phi} - \frac{\Delta I_{OUT(step)} \times t_t}{2} \right) (1 + TOL_{IND})
$$
\n(19)

$$
C_{\text{OUT}}(\text{min})(\text{sat}) = \frac{1}{27 \times 10^{-3}} \left(\frac{100 \times 10^{-9} \times 9.7^2}{2 \times 0.9 \times 1} - \frac{8.0 \times 1 \times 10^{-6}}{2} \right) (1 + 20\%) = 54.5 \,\mu\text{F}
$$
 (20)

In this case, choose $C_{OUT(min)} = 201.3 \mu F$ as the larger of the two values for the output capacitance.

 $\bar{\tilde{\mathcal{R}}}$ [9-1](#page-41-0) lists the three output capacitors chosen. 2 × 47-µF capacitors are placed close to the IC, giving a minimum effective capacitance of about 27 µF each. A single 220-µF capacitor is placed near the load to approximate the total decoupling capacitance required by a typical load. This 220-µF capacitor yields about 138 µF of effective capacitance. Together, the 192 µF of effective capacitance is very close to the required minimum value calculated above. For further calculations, use C_{OUT} = 192 µF.

方程式 21 checks that most of the output capacitance is placed at the load. If the ratio is less than 1, increase the capacitance at the load or place the device, output capacitance, and load next to each other such that there is no separation between the output capacitances.

$$
\frac{c_{\text{LOAD}}}{2 \times c_{\text{OUT}}} > 1\tag{21}
$$

$$
\frac{138 \times 10^{-6}}{2 \times (2 \times 27 \times 10^{-6})} > 1 = \text{True}
$$
 (22)

方程式 23 calculates the output voltage ripple, based on the effective output capacitance value.

$$
V_{OUT(p-p)} = \frac{I_{L(PP)}}{8 \times C_{OUT} \times f_{sw}}
$$
 (23)

$$
V_{OUT(p-p)} = \frac{3.4}{8 \times 192 \times 10^{-6} \times 2.25 \times 10^{6}} = 0.984 \ mV
$$
 (24)

The ripple is slightly higher in the application, due to the ESR and ESL in the output capacitors and the application board parasitics.

9.2.2.5 Selecting the Compensation Capacitor, C_{Comp1}

First, use [方程式](#page-46-0) 25 to calculate the bandwidth of the inner loop:

$$
BW_{\text{INNER}} = \frac{\tau}{2\pi \times \frac{L}{N\phi} \times C_{\text{OUT}}}
$$
 (25)

BW_{INNER} =
$$
\frac{12.5 \times 10^{-6}}{2\pi \times \frac{100 \times 10^{-9}}{1} \times 192 \times 10^{-6}} = 104 \text{ kHz}
$$
 (26)

Next, calculate the product of g_mR_{Comp1} :

$$
g_m \times R_{\text{Comp1}} = 1.5 \times 10^{-3} \times 806 = 1.21
$$
\n(27)

If g_mR_{Comp1} > than 1, use 方程式 28 to calculate the recommended value of C_{Comp1}, which sets a zero in the control loop. If g_mR_{Comp1} < 1, use 方程式 30 to calculate the recommended value of C_{Comp1}.

$$
C_{\text{Comp1}} = \frac{2}{\pi \times \text{BW}_{\text{INNER}} \times \text{g}_{\text{m}} \times \text{R}_{\text{Comp1}}^2}
$$
(28)

$$
C_{\text{Comp1}} = \frac{2}{\pi \times 104 \times 10^3 \times 1.5 \times 10^{-3} \times (806)^2} = 6.31 \text{ nF}
$$
\n(29)

The closest standard value is 6.8 nF.

$$
C_{\text{Comp1}} = \frac{2 \times g_{\text{m}}}{\pi \times BW_{\text{INNER}}} \tag{30}
$$

方程式 31 approximates the loop bandwidth.

$$
BW = BW_{\text{INNER}} \times 2 \times \left(1 + R_{Comp1} \times g_m\right) \tag{31}
$$

$$
BW = 104 \times 10^{3} \times 2 \times \left(1 + 806 \times 1.5 \times 10^{-3}\right) = 458 \, kHz \tag{32}
$$

9.2.2.6 Selecting the Compensation Capacitor, C_{Comp2}

The compensation capacitor, C_{Comp2} , is an optional capacitor that TI recommends the user include to bypass high-frequency noise away from the COMP pin. The value of this capacitor is not critical; 10-pF or 22-pF capacitors are designed for typical applications.

This capacitor can be made larger to suppress high-frequency zeros or resonances that occur in the system output voltage routing and decoupling network. 方程式 33 calculates the pole created by C_{Comp2}.

$$
f_{pole} = \frac{1}{2 \times \pi \times R_{Comp1} \times C_{Comp2}} \tag{33}
$$

9.2.3 Application Curves

 V_{IN} = 5.0 V, V_{OUT} = 0.9 V, T_A = 25°C, BOM = $\frac{1}{2}$ [9-1,](#page-41-0) unless otherwise noted.

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Tek Stop Tek PreVu ummmmmnn **ALANNNN** $\frac{2.00 \mu s}{\ln^{3-\pi} - 3.000000 \mu s}$ 5.00GS/s $\left[\begin{array}{c}$ Timeout $\frac{1.00 \mu s}{1.000000 \mu s}$ $\left[\frac{5.00 \text{GS/s}}{1 \text{M} \text{ points}}\right]$ $\left[\frac{3.00 \mu s}{270 \text{m} s} \right]$ $I_{\text{OUT}} = 10 \text{ A}$ $V_{\text{OUT}} = 0.9 \text{ V}$ $f_{\text{(SYNC)}} = 2 \text{ to } 2.5 \text{ MHz (random)}$ $I_{OUT} = 10 \text{ A}$ $V_{OUT} = 0.9 \text{ V}$ $f_{(SYNC)} = 1.8 \text{ MHz}$ 图 **9-32. Adding and Removing an External Clock** 图 **9-33. Synchronization to a Random External Clock** Trig'd Trig'd **Tek Run** Tek Run \sim $200 \mu s$ $\frac{500MS}{SM}$ $\frac{400 \text{ }\mu\text{s}}{1120.00 \text{ }\mu\text{s}}$ $\begin{bmatrix} 250\text{MS/s} \\ 1\text{M points} \end{bmatrix}$ \bullet 1.04 $\overline{2}$ \overline{J} $sson₁$ V_{IN} = 3.3 V V_{OUT} = 0.75 V 图 **9-34. Current Limit (Hiccup)** 图 **9-35. Start-Up Using EN Pin** Trig'd Trig'd Tek Run Te<u>k</u> Run v ou OUT $\frac{1.00 \text{ms}}{11.20.10 \text{ s}}$ $\sqrt{\frac{1.00 \text{ms}}{n^2 20.10}}$ $\frac{1}{\frac{500MS}{5}}$ $\frac{2}{\frac{300MS}{5}}$ $\frac{2}{\frac{1}{2}}$ $\frac{880m}{5}$ $\sqrt{\frac{500MS}{5M}}$ $\sqrt{2}$ $\frac{1}{880m}$ $V_{\text{OUT}} = 3.3 \text{ V}$ Load = 7.5 Ω $V_{\text{OUT}} = 3.3 \text{ V}$ Load = 7.5 Ω 图 **9-36. Shutdown Using EN Pin (Discharge** 图 **9-37. Shutdown Using EN Pin (Discharge Enabled) Disabled)**

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9.3 Typical Application Using Four TPSM8287Axx in Parallel Operation

图 **9-50. Typical Application Schematic** Copyright © 2024 Texas Instruments Incorporated $\frac{1}{4}$ J-JU: Typical Application Junematic denotion of the state of $\frac{E\ddot{\phi}\dot{\chi}}{B}$

表 **9-3. List of Components**

9.3.1 Design Requirements

表 9-4 lists the operating parameters for this application example with four TPSM8287A12BAS devices working in parallel to increase the output current.

表 **9-4. Design Parameters**

Preliminary Calculations

The maximum allowable deviation of the power supply is ±3.3%. The DC accuracy of the TPSM8287Axx is specified as ±0.8%, and therefore the maximum output voltage variation during a transient is given by:

$$
\Delta V_{\text{OUT}} = \pm V_{\text{OUT}} \times (\text{TOL}_{\text{VOUT}} - \text{TOL}_{\text{DC}}) \tag{34}
$$

$$
\Delta V_{\text{OUT}} = \pm V_{\text{OUT}} \times (3.3\% - 0.8\%) = \pm 15 \,\text{mV}
$$
\n(35)

[方程式](#page-58-0) 36 computes the peak-to-peak inductor current ripple, which is the greatest at the maximum input voltage:

$$
I_{L(PP)} = \frac{V_{OUT}}{V_{IN(max)}} \left(\frac{V_{IN(max)} - V_{OUT}}{L \times f_{sw} \times N\Phi} \right)
$$
(36)

$$
I_{L(PP)} = \frac{0.6}{6.0} \left(\frac{6.0 - 0.6}{100 \times 10^{-9} \times 1.5 \times 10^{6} \times 4} \right) = 0.9 A
$$
 (37)

The maximum load step occurs when the load step from the application occurs at exactly the same time as the peak (or trough) of the inductor ripple current, and is given by:

$$
\Delta I_{\text{OUT(max)}} = \Delta I_{\text{OUT(step)}} + \frac{\Delta I_{\text{L(PP)}}}{2} \tag{38}
$$

$$
\Delta I_{\text{OUT(max)}} = 30.0 + \frac{0.9}{2} = 30.5 \,\text{A} \tag{39}
$$

9.3.2 Detailed Design Procedure

The following subsections describe how to calculate the external components required to meet the specified transient requirements of a given application. The calculations include the worst-case variation of components and use the RMS method to combine the variation of uncorrelated parameters.

9.3.2.1 Selecting the Input Capacitors

The TPSM8287Axx devices feature a *butterfly* or parallel layout with two pairs of VIN and GND pins on opposite sides of the package.

The duty cycle of the converter is given by:

$$
D = \frac{V_{\text{OUT}}}{\eta \times V_{\text{IN}}}
$$
(40)

$$
D = \frac{0.60}{0.78 \times 2.7} = 0.284
$$
\n⁽⁴¹⁾

The value of input capacitance needed to meet any system-level input voltage ripple requirement is given by $\dot{\pi}$ 程式 42. For this example, the lowest input voltage and highest load current are used to generate a worst case input voltage ripple of 100 mV.

$$
C_{IN} = \frac{D \times (1 - D) \times I_{OUT}}{V_{IN(PP)} \times f_{sw}}
$$
(42)

$$
C_{IN} = \frac{0.284 \times (1 - 0.284) \times 12.0}{0.1 \times 1.5 \times 10^6} = 16.3 \,\mu\text{F}
$$
\n
$$
(43)
$$

The value of C_{IN} calculated with 方程式 42 is the *effective* capacitance after all derating, tolerance, and aging effects have been considered. In this parallel configuration it is important to distribute the calculated input capacitance equally accross all phases.

9.3.2.2 Selecting the Target Loop Bandwidth

The control loop bandwidth measures how quickly the device responds to a change in output voltage. With the TPSM8287Axx external compensation, the loop bandwidth is adjustable to balance the tradeoff of a fast response versus stability and ringing. The $R_{\text{Com}1}$ resistor and output capacitance are the primary means of adjusting the loop bandwidth.

TI recommends setting the target loop bandwidth to 200 kHz for a simple design. If strong load transients are expected in the application, the target bandwidth can be set as high as ¼ of the switching frequency. A target bandwidth of 375 kHz is used for this example design.

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9.3.2.3 Selecting the Compensation Resistor

Use $\overline{B} \boxtimes \overline{A}$ 44 to calculate the recommended value of compensation resistor, R_{Comp1}:

$$
R_{\text{Comp1}} = \frac{1}{g_{\text{m}}} \left(\frac{\pi \times \Delta I_{\text{OUT}(step)} \times L}{4 \times \tau \times \Delta V_{\text{OUT}} \times N\Phi} - 1 \right) \left(1 + \sqrt{\text{TOL}_{\text{IND}}^2 + \text{TOL}_{\tau}^2} \right) \tag{44}
$$

$$
R_{\text{Comp1}} = \frac{1}{1.5 \times 10^{-3}} \left(\frac{\pi \times 30.0 \times 10^{10} \times 10^{-9}}{4 \times 12.5 \times 10^{-6} \times 15 \times 10^{-3} \times 4} - 1 \right) \left(1 + \sqrt{20\%^{2} + 30\%^{2}} \right) = 1943 \,\Omega \tag{45}
$$

Picking a standard component above the calculated value, a 2000-Ohm resistor is chosen in this example. The selected value must be used for the further calculations.

9.3.2.4 Selecting the Output Capacitors

If the converter remains in regulation, the minimum required output capacitance is given by:

$$
C_{OUT(min)(reg)} = \left(\frac{\tau \times (1 + g_m \times R_{Comp1})}{2 \times \pi \times \frac{L}{N\phi} \times BW_{\tau}}\right) \left(1 + \sqrt{TOL_{\tau}^2 + TOL_{IND}^2 + TOL_{FSW}^2}\right)
$$
(46)

$$
C_{OUT(min)(reg)} = \left(\frac{12.5 \times 10^{-6} \times \left(1 + 1.5 \times 10^{-3} \times 2000\right)}{2 \times \pi \times \frac{100 \times 10^{-9}}{4} \times 375 \times 10^{3}}\right) \left(1 + \sqrt{30\%^{2} + 20\%^{2} + 10\%^{2}}\right) = 1166 \,\mu\text{F}
$$
\n(47)

If the converter loop saturates, the minimum output capacitance is given by:

$$
C_{OUT(min)(sat)} = \frac{1}{\Delta V_{OUT}} \left(\frac{L \times \Delta I_{OUT(max)}}{2 \times V_{OUT} \times N\Phi} - \frac{\Delta I_{OUT(step)} \times t_t}{2} \right) (1 + TOL_{IND})
$$
\n(48)

$$
C_{\text{OUT}}(\text{min})(\text{sat}) = \frac{1}{15 \times 10^{-3}} \left(\frac{100 \times 10^{-9} \times 30.5^2}{2 \times 0.6 \times 4} - \frac{30.0 \times 1 \times 10^{-6}}{2} \right) (1 + 20\%) = 345 \,\mu\text{F}
$$

In this case, choose $C_{\text{OUT}(min)}$ = 1166 µF as the larger of the two values for the output capacitance.

表 [9-3](#page-57-0) lists the output capacitors chosen. 2×47 -µF capacitors are placed close to each of the four modules, giving a minimum effective capacitance of about 27 µF each. Five 220-µF capacitors and five 47-µF are placed near the load to approximate the total decoupling capacitance required by a typical load. Each of the 220-µF capacitors yield about 138 µF of effective capacitance. Together, the 1041 µF of effective capacitance is very close to the required minimum value calculated above. For further calculations, use C_{OUT} = 1041 µF.

方程式 50 checks that most of the output capacitance is placed at the load. If the ratio is less than 1, increase the capacitance at the load or place the device, output capacitance, and load next to each other such that there is no separation between the output capacitances.

$$
\frac{C_{\text{LOAD}}}{2 \times C_{\text{OUT}}} > 1\tag{50}
$$

$$
\frac{5 \times 27 \times 10^{-6} + 5 \times 138 \times 10^{-6}}{2 \times (4 \times 2 \times 27 \times 10^{-6})} > 1 = \text{True}
$$
 (51)

方程式 52 calculates the output voltage ripple, based on the effective output capacitance value.

$$
V_{OUT(p-p)} = \frac{I_{L(PP)}}{8 \times C_{OUT} \times f_{sw}}
$$
\n(52)

$$
V_{OUT(p-p)} = \frac{0.9}{8 \times 1041 \times 10^{-6} \times 1.5 \times 10^{6}} = 0.072 \, mV \tag{53}
$$

The ripple is slightly higher in the application due to the ESR and ESL in the output capacitors and the application board parasitics.

9.3.2.5 Selecting the Compensation Capacitor, C_{Comp1}

First, use 方程式 54 to calculate the bandwidth of the inner loop:

$$
BW_{INNER} = \frac{\tau}{2\pi \times \frac{L}{N\phi} \times C_{OUT}}\tag{54}
$$

BW_{INNER} =
$$
\frac{12.5 \times 10^{-6}}{2\pi \times \frac{100 \times 10^{-9}}{4} \times 1041 \times 10^{-6}} = 76.4 \text{ kHz}
$$
(55)

Next, calculate the product of g_mR_{Comn1} :

$$
g_m \times R_{\text{Comp1}} = 1.5 \times 10^{-3} \times 2000 = 3.0
$$
\n(56)

If g_mR_{Comp1} > than 1, use 方程式 57 to calculate the recommended value of C_{Comp1}, which sets a zero in the control loop. If g_mR_{Comp1} < 1, use 方程式 59 to calculate the recommended value of C_{Comp1}.

$$
C_{\text{Comp1}} = \frac{2}{\pi \times \text{BW}_{\text{INNER}} \times \text{g}_{\text{m}} \times \text{R}_{\text{Comp1}}^2}
$$
(57)

$$
C_{\text{Comp1}} = \frac{2}{\pi \times 76.4 \times 10^3 \times 1.5 \times 10^{-3} \times (2000)^2} = 1.39 \text{ nF}
$$
\n(58)

The closest standard value is 1.5 nF.

$$
C_{\text{Comp1}} = \frac{2 \times g_{\text{m}}}{\pi \times BW_{\text{INNER}}} \tag{59}
$$

方程式 60 approximates the loop bandwidth.

$$
BW = BW_{\text{INNER}} \times 2 \times \left(1 + R_{Comp1} \times g_m\right) \tag{60}
$$

$$
BW = 76.4 \times 10^3 \times 2 \times \left(1 + 2000 \times 1.5 \times 10^{-3}\right) = 612 \, kHz \tag{61}
$$

9.3.2.6 Selecting the Compensation Capacitor, C_{Comp2}

The compensation capacitor, C_{Comp2} , is an optional capacitor that TI recommends the user include to bypass high-frequency noise away from the COMP pin. The value of this capacitor is not critical; 10-pF or 22-pF capacitors are designed for typical applications.

This capacitor can be made larger to suppress high-frequency zeros or resonances that occur in the system output voltage routing and decoupling network. 方程式 62 calculates the pole created by C_{Comp2}.

$$
f_{pole} = \frac{1}{2 \times \pi \times R_{Comp1} \times C_{Comp2}} \tag{62}
$$

9.3.3 Application Curves

V_{IN} = 5.0 V, V_{OUT} = 0.6 V, T_A = 25°C, BOM = $\frac{1}{\sqrt{6}}$ [9-3,](#page-57-0) 4 × TPSM8287A12BAS in parallel operation, unless otherwise noted.

62 *[提交文档反馈](https://www.ti.com/feedbackform/techdocfeedback?litnum=ZHCSPT6D&partnum=TPSM8287A06)* Copyright © 2024 Texas Instruments Incorporated

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[ZHCSPT6D](https://www.ti.com.cn/cn/lit/pdf/ZHCSPT6) – JULY 2023 – REVISED JUNE 2024

9.4 Power Supply Recommendations

The TPSM8287Axx family has no special requirements for the input power supply. The output current rating of the input power supply must be rated according to the supply voltage and current requirements of the TPSM8287Axx. For proper operation, the input voltage must be at least 1.4 V above the selected output voltage.

9.5 Layout

9.5.1 Layout Guidelines

A proper layout is critical for the operation of any switched mode power supply, especially at high switching frequencies. Therefore, the PCB layout of the TPSM8287Axx demands careful attention to make sure of best performance. A poor layout can lead to issues like the following:

- Bad line and load regulation
- Instability
- Increased EMI radiation
- Noise sensitivity

Refer to the *[Five Steps to a Great PCB Layout for a Step-Down Converter](https://www.ti.com/lit/pdf/SLYT614)* analog design journal for a detailed discussion of general best practices. The following are specific recommendations for the TPSM8287Axx:

- Place the input capacitors as close as possible to the VIN and GND pins of the device. This placement is the most critical component placement. Route the input capacitors directly to the VIN and GND pins avoiding vias.
- Place the output capacitors close to the VOUT and GND pins and route them directly avoiding vias.
- Place the IC close to the load to minimize the power loss from voltage drop on the output and to minimize parasitic inductance between the output capacitors at the TPSM8287Axx and those at the load.
- Use GND vias under the three exposed thermal pads to improve thermal performance. Directly connect the GND pins to the exposed thermal pad with copper on the top PCB layer.
- Route the VOSNS and GOSNS remote sense lines as a differential pair and connect them to the lowest impedance point at the load. Do not route the VOSNS and GOSNS traces close to any switch nodes, the input capacitors, clock signals, or other aggressor signals.
- Connect the compensation components between COMP and GOSNS. Do not connect the compensation components directly to power ground.
- Place the VSETx resistors (and SYNC_OUT resistor in the secondary devices) close to the TPSM8287Axx to minimize parasitic capacitance.
- Route VOSNS, GOSNS, and COMP directly to keep them short and avoid noisy aggressor signals in the stacked configuration.
- Refer to \mathbb{S} [9-57](#page-64-0) for an example of component placement, routing, and thermal design.
- See the recommended land pattern for the TPSM8287Axx at the end of this data sheet. For best manufacturing results, create the pads as solder mask defined (SMD) when some pins (such as VIN, VOUT, and GND) are connected to large copper planes. Using SMD pads keeps each pad the same size and avoids solder pulling the device during reflow.

9.5.2 Layout Example

图 **9-57. Layout Example**

10 Device and Documentation Support

10.1 Device Support

10.1.1 第三方产品免责声明

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10.2 Documentation Support

10.2.1 Related Documentation

For related documentation see the following:

- Texas Instruments, *[Achieving a clean startup by using a DC/DC converter with a precise enable-pin threshold](https://www.ti.com/lit/pdf/SLYT730)* analog design journal
- Texas Instruments, *[Five Steps to a Great PCB Layout for a Step-Down Converter](https://www.ti.com/lit/pdf/SLYT614)* analog design journal

10.3 接收文档更新通知

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10.4 支持资源

TI E2E™ [中文支持论坛](https://e2e.ti.com)是工程师的重要参考资料,可直接从专家处获得快速、经过验证的解答和设计帮助。搜索 现有解答或提出自己的问题,获得所需的快速设计帮助。

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10.5 Trademarks

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10.6 静电放电警告

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ESD 的损坏小至导致微小的性能降级,大至整个器件故障。精密的集成电路可能更容易受到损坏,这是因为非常细微的参 数更改都可能会导致器件与其发布的规格不相符。

10.7 术语表

TI [术语表](https://www.ti.com/lit/pdf/SLYZ022) 本术语表列出并解释了术语、首字母缩略词和定义。

11 Revision History

注:以前版本的页码可能与当前版本的页码不同

Changes from Revision A (November 2023) to Revision B (December 2023) Page

- Changed Output Voltage ramp from 0.425 / 0.54 / 0.62 ms to 0.46 / 0.54 / 0.62 ms (MIN / TYP / MAX)..........[7](#page-6-0)
- Changed Output Voltage ramp from 0.85 / 1.0 / 1.15 ms to 0.88 / 1.04 / 1.20 ms (MIN / TYP / MAX)..............[7](#page-6-0)
- Changed Output Voltage ramp from 1.[7](#page-6-0) / 2.0 / 2.3 ms to 1.73 / 2.04 / 2.35 ms (MIN / TYP / MAX)..................7
- Changed Output Voltage ramp from 3.4 / 4.0 / 4.6 ms to 3.43 / 4.04 / 4.65 ms (MIN / TYP / MAX)..................[7](#page-6-0)

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures. "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION

ISTRUMENTS

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

PACKAGE MATERIALS INFORMATION

www.ti.com 16-Jun-2024

PACKAGE OUTLINE

RDW0039A B3QFN - 4 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

RDW0039A B3QFN - 4 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RDW0039A B3QFN - 4 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

PACKAGE OUTLINE

RDV0039A B0QFN - 1.85 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

RDV0039A B0QFN - 1.85 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RDV0039A B0QFN - 1.85 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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